

# **Product Specification**

# 43 Gb/s High Gain Photoreceiver

# XPRV2022A

## PRODUCT FEATURES

- PIN / TIA photoreceiver module
- 33 GHz bandwidth
- 500 V/W conversion gain
- SMD package with V® connector
- AC coupled output

#### **APPLICATIONS**

- 43 Gb/s communication systems (OC-768)
- Transponder and line card designs
- Laboratory test equipment



The photoreceiver module XPRV2022(A) is a single ended front-end with a high gain of typically 500 V/W and a bandwidth of 33 GHz. The photoreceiver module XPRV2022(A) contains a waveguide-integrated PIN-photodiode (PD) and a transimpedance amplifier (TIA) with limiting output buffer. An integrated feedback loop optimizes the performance in the frequency and/or time domain with respect to different optical input power. Due to the limiting output buffer the output voltage swing is limited to approx. 400 mV. Incorporated blocking capacitors enable AC output coupling.

### ORDERING INFORMATION

zz:

#### XPRV2022A-Vy-zz

A: = AC coupled

Vy: VF = female V Connector® (standard)

VM = male V Connector<sup>®</sup> FP = FC/PC (standard)

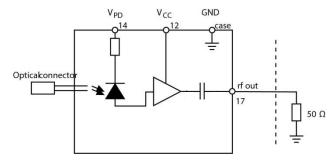
other connectors available upon request



## I. Pin Description

| # Pin                | Symbol          | Description                                     |
|----------------------|-----------------|---|
| 1,3,16               | N/C             | not connected, 100 nF to GND, max +5 V          |
| 2,4,5,6,11,13,<br>15 | GND             | ground  |
| 7,8,9,10             | RFU             | reserved for future use - please do not connect |
| 12                   | V <sub>cc</sub> | amplifier supply                                |
| 14                   | $V_{PD}$        | photodiode supply                               |
| 17                   | out             | inverting RF output, V® connector               |

## II. Block Diagram



## **III.** Absolute Maximum Ratings

| Parameter                           | Symbo<br>I       | Condition                    | Min. | Тур. | Max. | Unit |
|-------------------------------------|------------------|------------------------------|------|------|------|------|
| Photodiode Reverse Voltage          | $V_{PD}$         | V <sub>CC</sub> = Min to Max | 2    |      | 4    | V    |
| Amplifier Supply Voltage            | V <sub>CC</sub>  | V <sub>PD</sub> = 2 V to Max | 0    |      | 4    | V    |
| Maximum Average Optical Input Power | P <sub>opt</sub> | NRZ                          |      |      | 6    | dBm  |
| Electro Static Discharge            | V <sub>ESD</sub> | C= 100 pF, R=<br>1.5 kΩ HBM  | -250 |      | 250  | V    |
| Fiber Bend Radius                   |                  |                              | 16   |      |      | mm   |



# **Notice**

Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operations section for extended periods of time may affect reliability.

The inherent design of this component causes it to be sensitive to electrostatic discharge (ESD). To prevent ESD-induced damage and/or degradation to equipment, take normal ESD precautions when handling this product.



## **IV.** Environmental Conditions

| Parameter                  | Symbo<br>I        | Condition      | Min. | Тур. | Max. | Unit |
|----------------------------|-------------------|----------------|------|------|------|------|
| Operating Case Temperature | T <sub>Case</sub> |                | 0    |      | 75   | °C   |
| Relative Humidity          | RH                | non condensing | 5    |      | 85   | %    |
| Storage Temperature        | T <sub>sto</sub>  |                | -40  |      | 85   | °C   |

## V. Operating Conditions

| Parameter                         | Symbo<br>I       | Condition | Min. | Тур. | Max. | Unit |
|-----------------------------------|------------------|-----------|------|------|------|------|
| Amplifier Supply Voltage          | $V_{CC}$         |           | 3.1  | 3.3  | 3.5  | V    |
| Operating Wavelength Range        | λ                |           | 1480 |      | 1620 | nm   |
| Average Optical Input Power Range | P <sub>opt</sub> |           | -10  |      | 3    | dBm  |
| Photodiode Reverse Voltage        | $V_{PD}$         |           | 3.1  | 3.3  | 3.5  | V    |

# VI. Electro-Optical Specifications<sup>1</sup>

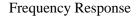
| Parameter                       | Symbo              | Condition                 | Min. | Тур. | Max. | Unit |
|---------------------------------|--------------------|---------------------------|------|------|------|------|
| Conversion Gain                 | CG                 | 2)                        | 300  | 500  |      | V/W  |
| Photodiode DC Responsivity      | R                  | optimum polarization      | 0.5  |      | 0.75 | A/W  |
| Polarization Dependent Loss     | PDL                |                           |      | 0.3  | 0.9  | dB   |
| Optical Return Loss             | ORL                |                           | 27   |      |      | dB   |
| 3dB Cut-off Frequency           | f <sub>3dB</sub>   | 2)                        | 30   | 30   |      | GHz  |
| Lower Frequency cut off         | f <sub>3dB_L</sub> |                           |      |      | 100  | kHz  |
| Output Reflection Coefficient   | 0                  | 0.5 - 15 GHz              |      | -15  | -10  | dB   |
| Output Reflection Coefficient   | S <sub>22</sub>    | 15 - 30 GHz               |      | -6   | -2   | ub   |
| Output Voltage Swing            | $V_{out}$          | P <sub>opt</sub> ≥ 0 dBm  |      | 400  | 600  | mV   |
| Equivalent Input Noise Density  | i                  |                           |      |      | 40   | pA/√ |
| Equivalent input ivoise Bensity | noise              |                           |      |      | 40   | Hz   |
| Overload                        | P <sub>overl</sub> | 3)                        | 3    |      |      | dBm  |
| Photodiode Dark Current         | l <sub>dark</sub>  | T <sub>Case</sub> = 25 °C |      | 8    | 200  | nA   |
| Power Consumption               | P <sub>con</sub>   | V <sub>cc</sub> = max     |      |      | 0.4  | W    |

## Notes:

- 1.  $\lambda = 1550 \text{ nm}, V_{bias} = 3.3 \text{ V}, T = 25 ^{\circ}\text{C}$
- 2. Measured using Agilent 860330A 50 GHz Lightwave component analyzer
- Evaluated from NRZ eye diagram and BER measurement at 40 Gb/s (BER 10<sup>-12</sup>, PRBS 2<sup>31</sup>-1, back to back)



#### VII. **Typical Performance Curves**



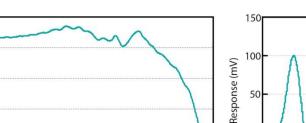
0

-6

-9

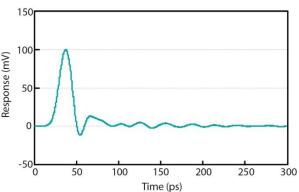
-12 L

Response (dB) -3



30

## Pulse Response

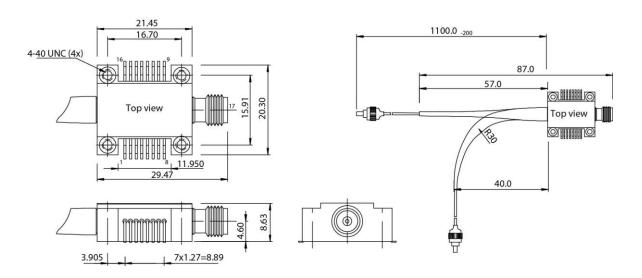


#### VIII. **Mechanical Specifications**

20

Frequency (GHz)

10



40

All dimensions in mm.

#### IX. Accessories

The Finisar Evaluation Kit EVA-XPRV serves as an easy-to-use utility to characterize the Finisar photoreceiver XPRV2022A under laboratory conditions. The kit consists of a PCB (printed circuit board), a DC cable set and 4 socket head screws 4-40 UNC.



## **ORDERING INFORMATION**

EVA - XPRV



## X. Revision History

| Revision      | Date       | Description   |  |  |  |  |  |
|---------------|------------|---|--|--|--|--|--|
| A1            | 04/09/2014 | Document created.   |  |  |  |  |  |
| A2 05/18/2017 |            | Updated version with new Finisar Logo                         |  |  |  |  |  |
| AZ            | 03/16/2017 | Modified block diagram and removed DC coupled version (EOL'd) |  |  |  |  |  |

## Notes

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## **For More Information**

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